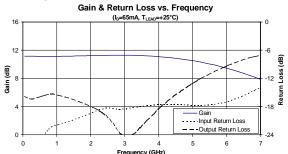


Product Description

Sirenza Microdevices' SNA-686 is a GaAs HBT MMIC Amplifier housed in a low-cost, surface-mountable plastic package. The heterojunction increases breakdown voltage and minimizes leakage current between junctions. Cancellation of emitter junction non-linearities results in higher suppression of intermodulation products.

The use of an external resistor allows for bias flexibility and stability. These unconditionally stable amplifiers are designed for use as general purpose 50 ohm gain blocks.

Also available in chip form (SNA-600), its small size (0.38mm x 0.38mm) and gold metallization make it an ideal choice for use in hybrid circuits.



SNA-686 DC-6 GHz, Cascadable **GaAs HBT MMIC Amplifier**

OBSOLETE See Obsolescence Notice for Replacements

Product Features

- Patented GaAs HBT Technology
- Cascadable 50 Ohm Gain Block
- 34 dBm Output IP3 @ 850 MHz
- Operates From Single Supply
- Low Cost Surface Mount Plastic Package

Applications

• Cellular, PCS, CDPD, Wireless Data, SONET

	Frequency (GHZ)					
Symbol	Parameter	Frequency	Units	Min.	Тур.	Max.
P _{1dB}	Output Power at 1dB Compression	850 MHz 1950 MHz 2400 MHz	dBm dBm dBm	15.7	17.6 17.7 17.4	
IP_3	Third Order Intercept Point	850 MHz 1950 MHz 2400 MHz	dBm dBm dBm	29.1	34.0 32.1 30.0	
S ₂₁	Small Signal Gain	850 MHz 1950 MHz 2400 MHz	dB dB dB	10.0 10.1	11.1 11.2 11.3	12.2 12.3
Bandwidth	(Determined by $S_{_{11}}$, $S_{_{22}}$ Values)		MHz		6000	
VSWR _{IN}	Input VSWR	DC-6000 MHz	-		1.3:1	
SWR _{out}	Output VSWR	DC-6000 MHz	-		1.4:1	
\$ ₁₂	Reverse Isolation	850 MHz 1950 MHz 2400 MHz	dB dB dB		16.3 16.5 16.6	
NF	Noise Figure	1950 MHz	dB		7.3	8.8
V _D	Device Operating Voltage		V	5.0	5.3	5.6
I _D	Device Operating Current		I	58	65	72
R _{TH} , j-l	Thermal Resistance (junction - lead)		° C/W		261	
Test Cond	litions: $V_s = 8 V$ $I_D = 65$ $R_{BIAS} = 43 Ohms$ $T_L = 250$		ne Spacing 50 Ohms	= 1 MHz, Po	out per tone =	0 dBm

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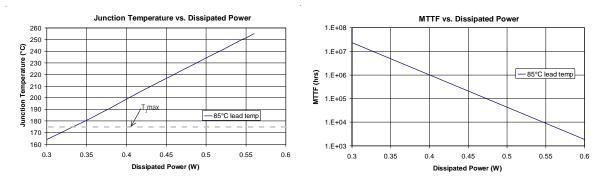


Typical RF Performance at Key Operating Frequencies

			Frequency (MHz)					
Symbol	Parameter	Unit	100	500	850	1950	2400	3500
G	Small Signal Gain	dB	11.1	11.1	11.1	11.2	11.3	11.3
OIP ₃	Output Third Order Intercept Point	dBm		35.0	34.0	32.1	30.0	
P _{1dB}	Output Power at 1dB Compression	dBm		17.5	17.6	17.7	17.4	
IRL	Input Return Loss	dB	29.5	25.2	22.3	19.6	18.4	17.9
ORL	Output Return Loss	dB	16.0	15.9	15.3	17.8	19.6	22.2
S ₁₂	Reverse Isolation	dB	16.2	16.2	16.3	16.5	16.6	17.0
NF	Noise Figure	dB		7.2	7.3	7.3		
Tes	Test Conditions: $V_s = 8v$ $I_p = 65mA$ Typ. OIP3 Tone Spacing = 1 MHz, Pout per tone = 0 dBm $R_{BIAS} = 43 \text{ Ohms}$ $T_L = 25^{\circ}\text{C}$ $Z_s = Z_L = 50 \text{ Ohms}$							

Absolute Maximum Ratings	Parameter	Absolute Limit
Absolute Maximum Ratings	Max. Device Current (I_{D})	120 mA
Operation of this device beyond any one of these limits may	Max. Device Voltage (V_{D})	7 V
cause permanent damage. For reliable continous operation, the device voltage and current must not exceed the maximum	Max. RF Input Power	+16 dBm
operating values specified in the table on page one.	Max. Junction Temp. (T_J)	+175°C
Bias Conditions should also satisfy the following expression:	Operating Temp. Range (T_L)	-40°C to +85°C
$I_{D}V_{D} < (T_{J} - T_{L}) / R_{T_{H}}$ jl	Max. Storage Temp.	+150°C

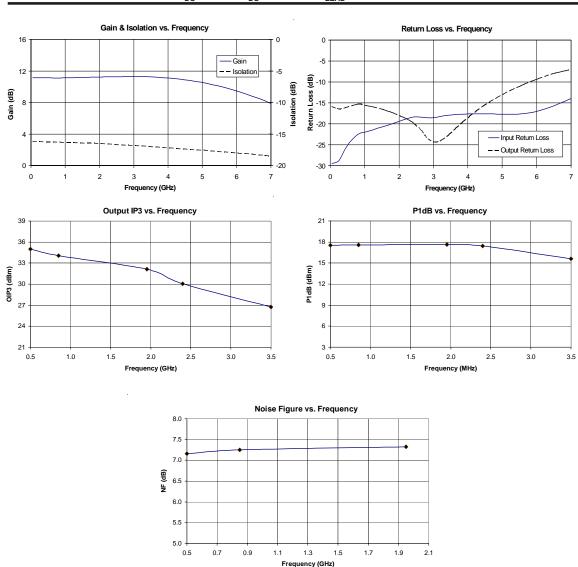
NOTE: While the SNA-686 can be operated at different bias currents, 65 mA is the recommended bias for lower junction temperature and longer life. This reflects typical operating conditions which we have found to be an optimal balance between high IP3 and MTTF. In general, MTTF is improved to more than 100,000 hours when biasing at 65 mA and operating up to 85°C ambient temperature.



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Typical RF Performance ($V_{DS} = 5.3V$, $I_{DS} = 65mA$, $T_{LEAD} = 25^{\circ}$ C)

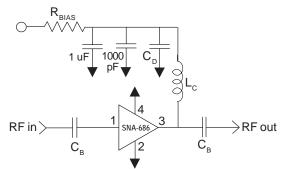
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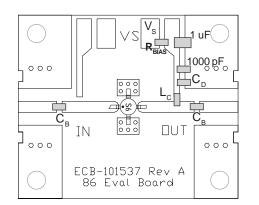
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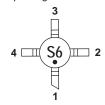
Typical Application Circuit





Part Identification Marking

The part will be marked with an "S6" designator on the top surface of the package.



Caution: ESD sensitive

Appropriate precautions in handling, packaging and testing devices must be observed.

Application Circuit Element Values

Reference	Frequency (Mhz)						
Designator	500	850	1950	2400	3500		
C _B	220 pF	100 pF	68 pF	56 pF	39 pF		
C _D	100 pF	68 pF	22 pF	22 pF	15 pF		
L	68 nH	33 nH	22 nH	18 nH	15 nH		

Recommended Bias Resistor Values for I_{D} =65mA R _{BIAS} =(V _S -V _D) / I _D					
Supply Voltage(V_s)	8 V	9 V	12 V	15 V	
R _{BIAS}	43 Ω	56 Ω	100 Ω	150Ω	

Note: R_{BIAS} provides DC bias stability over temperature.

Mounting Instructions

- 1. Use a large ground pad area under device pins 2 and 4 with many plated through-holes as shown.
- We recommend 1 or 2 ounce copper. Measurements for this data sheet were made on a 31 mil thick FR-4 board with 1 ounce copper on both sides.

Pin #	Function	Description
1	RF IN	RF input pin. This pin requires the use of an external DC blocking capacitor chosen for the frequency of operation.
2, 4	GND	Connection to ground. For optimum RF performance, use via holes as close to ground leads as possible to reduce lead inductance.
3	RF OUT/ BIAS	RF output and bias pin. DC voltage is present on this pin, therefore a DC blocking capacitor is necessary for proper operation.

Part Number Ordering Information

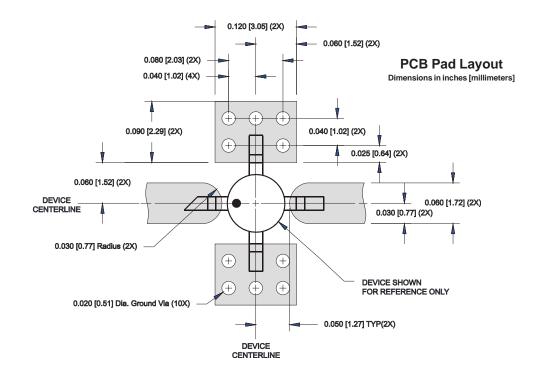
Part Number	Reel Size	Devices/Reel
SNA-686	7"	1000

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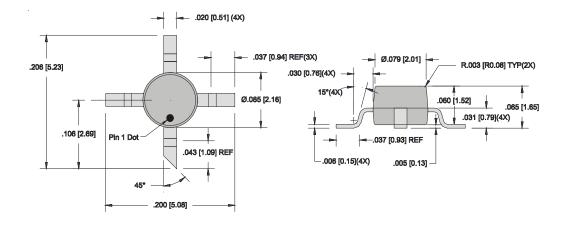
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Nominal Package Dimensions Dimensions in inches [millimeters] Refer to drawing posted at www.sirenza.com for tolerances.



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